

SQM40014EM_GE3 Datasheet

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DiGi Electronics Part Number	SQM40014EM_GE3-DG
Manufacturer	Vishay Siliconix
Manufacturer Product Number	SQM40014EM_GE3
Description	MOSFET N-CH 40V 200A TO263-7
Detailed Description	N-Channel 40 V 200A (Tc) 375W (Tc) Surface Moun TO-263-7

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
SQM40014EM_GE3	Vishay Siliconix
Series:	Product Status:
TrenchFET®	Active
FET Type:	Technology:
N-Channel	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss):	Current - Continuous Drain (ld) @ 25°C:
40 V	200A (Tc)
Drive Voltage (Max Rds On, Min Rds On):	Rds On (Max) @ ld, Vgs:
10V	1mOhm @ 35A, 10V
Vgs(th) (Max) @ ld:	Gate Charge (Qg) (Max) @ Vgs:
3.5V @ 250µA	250 nC @ 10 V
Vgs (Max):	Input Capacitance (Ciss) (Max) @ Vds:
±20V	15525 pF @ 25 V
FET Feature:	Power Dissipation (Max):
-	375W (Tc)
Operating Temperature:	Grade:
-55°C ~ 175°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Supplier Device Package:	Package / Case:
TO-263-7	TO-263-7, D2PAK (6 Leads + Tab)
Base Product Number:	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
ECCN:	HTSUS:
EAR99	8541.29.0095



RoHS

COMPLIANT HALOGEN

FREE

Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

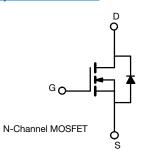


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PRODUCT SUMMARY			
V _{DS} (V)	40		
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.00100		
I _D (A)	200		
Configuration	Single		
Package	TO-263-7L		

FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATING	S (T _C = 25 °C, unless	s otherwise noted)	
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V _{DS}	40	V
Gate-source voltage		V _{GS}	± 20	v
Continuous drain current ^a	T _C = 25 °C	L.	200	
Continuous drain current "	T _C = 125 °C	- I _D	200	
Continuous source current (diode conduction) ^a		I _S	200	А
Pulsed drain current ^b		I _{DM}	260	
Single pulse avalanche current	L = 0.1 mH	I _{AS}	100	
Single pulse avalanche energy		E _{AS}	500	mJ
Maximum power dissipation ^b	T _C = 25 °C	PD	375	W
maximum power dissipation ~	T _C = 125 °C		125	vv
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W
Junction-to-case (drain)		R _{thJC}	0.4	0/10

Notes

a. Package limited

b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$

c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static		•			•	•	
Drain-source breakdown voltage	V _{DS}	V _{GS} =	= 0 V, I _D = 250 μA	40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	= V _{GS} , I _D = 250 μΑ	2.5	3.0	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, $V_{GS} = \pm 20$ V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	300	μA
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	100	-	-	Α
		V _{GS} = 10 V	I _D = 35 A	-	0.00084	0.00100	
Drain-source on-state resistance ^a	R _{DS(on)}	$V_{GS} = 10 V$	I _D = 35 A, T _J = 125 °C	-	-	0.00140	Ω
		V _{GS} = 10 V	I _D = 35 A, T _J = 175 °C	-	-	0.00164	
Forward transconductance b	9 _{fs}	V _{DS} = 15 V, I _D = 30 A		-	196	-	S
Dynamic ^b							
Input capacitance	C _{iss}			-	11 938	15 525	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	11 163	14 520	pF
Reverse transfer capacitance	C _{rss}			-	282	370	
Total gate charge ^c	Qg			-	158	250	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 100 \text{ A}$	-	44	-	nC
Gate-drain charge ^c	Q _{gd}			-	22	-	
Gate resistance	Rg	f = 1 MHz		2.70	5.44	8.20	Ω
Turn-on delay time ^c	t _{d(on)}			-	16	25	
Rise time ^c	tr	$V_{DD} = 20 \text{ V}, \text{ R}_{L} = 0.2 \Omega$		-	10	17	nc
Turn-off delay time ^c	t _{d(off)}	I _D ≅ 100 A,	V_{GEN} = 10 V, R_g = 1 Ω	-	103	160	ns
Fall time ^c	t _f			-	61	95	
Source-Drain Diode Ratings and Chara	cteristics ^b						
Pulsed current ^a	I _{SM}			-	-	260	Α
Forward voltage	V _{SD}	$I_F = 60 \text{ A}, V_{GS} = 0 \text{ V}$		-	0.81	1.5	V
Body diode reverse recovery time	t _{rr}			-	165	350	ns
Body diode reverse recovery charge	Q _{rr}	- I _F = 30 A, di/dt = 100 A/μs		-	530	1100	nC
Reverse recovery fall time	t _a	IF = 30	A, uvul = 100 Avus	-	66	-	200
Reverse recovery rise time	t _b			-	99	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-6.2	-	Α

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$

b. Guaranteed by design, not subject to production testing

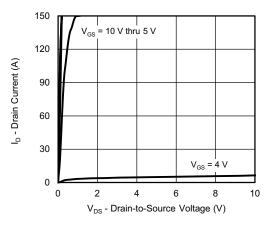
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

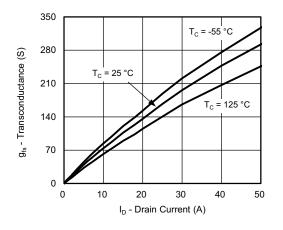


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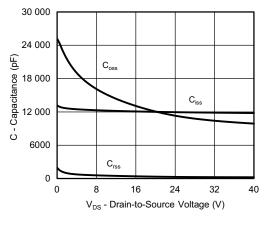
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



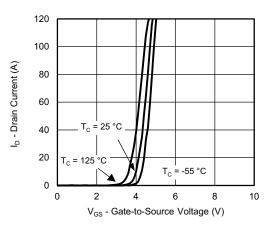
Output Characteristics



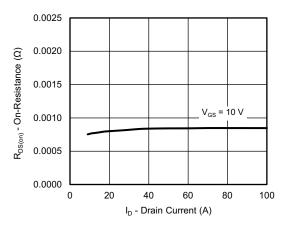
Transconductance



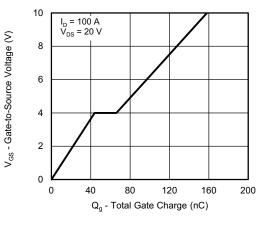
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current



Gate Charge

S17-0968-Rev. A, 03-Jul-17

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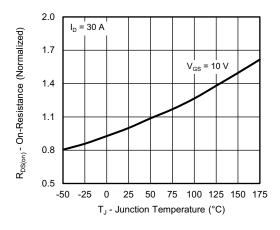
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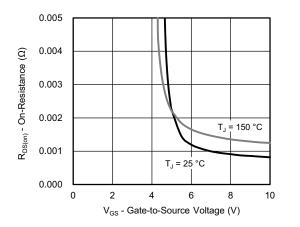


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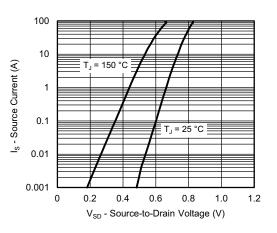
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



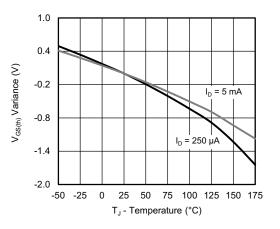
On-Resistance vs. Junction Temperature

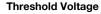


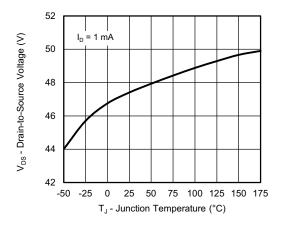
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage





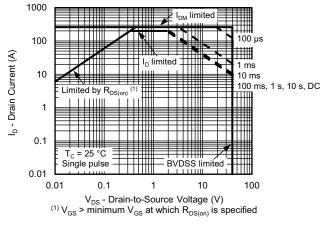


Drain Source Breakdown vs. Junction Temperature

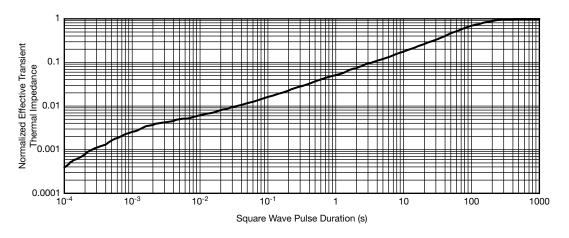


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)







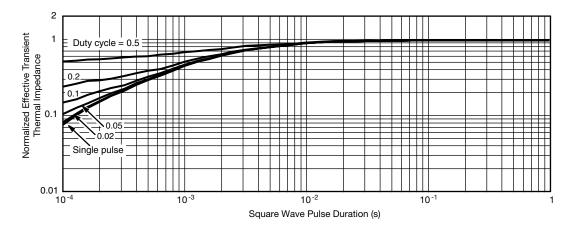
Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

S17-0968-Rev. A, 03-Jul-17

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

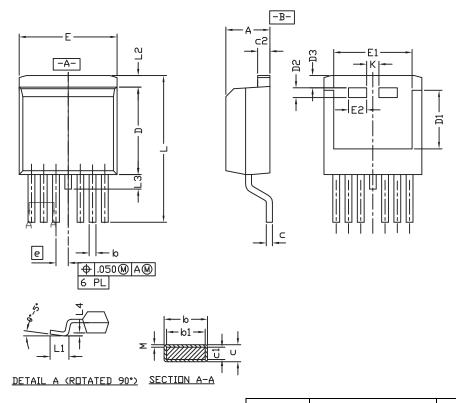
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Package Information

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D²PAK (TO-263-7L) Case Outline



Notes

- 1. Plane B includes maximum features of heat sink tab and plastic
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils
- 3. Pin to pin coplanarity max. 4 mils
- 4. Lead thickness 25 mils
- 5. For SUM part numbers lead thickness is 24 mils to 29 mils
- 6. For reference only
- 7. Use inches as the primary measurement
- 8. This feature is only for SUM

	INCHES		MILLIMETERS	
DIM.	MIN.	MAX.	MIN.	MAX.
А	0.160	0.190	4.064	4.826
b	0.020	0.039	0.508	0.990
b1	0.020	0.035	0.508	0.889
c* SUB	0.012	0.018	0.305	0.457
c* SUM	0.022	0.028	0.559	0.711
c1	0.018	0.025	0.457	0.635
c2	0.045	0.055	1.143	1.397
D	0.340	0.380	8.636	9.652
D1	0.260	0.280	6.604	7.112
D2	0.046	0.050	1.168	1.270
D3	0.045	0.055	1.143	1.397
E	0.380	0.410	9.652	10.414
E1	0.245	-	6.223	-
E2	0.072	0.078	1.829	1.981
е	0.050 BSC		1.27 BSC	
K	0.045	0.055	1.143	1.397
L	0.575	0.625	14.605	15.875
L1	0.090	0.110	2.286	2.794
L2	0.040	0.055	1.016	1.397
L3	0.050	0.070	1.270	1.778
L4	0.010 BSC		0.254 BSC	
М	-	0.002	-	0.050
ECN: T22-0 DWG: 6006	0410-Rev. D, 6	19-Sep-2022		

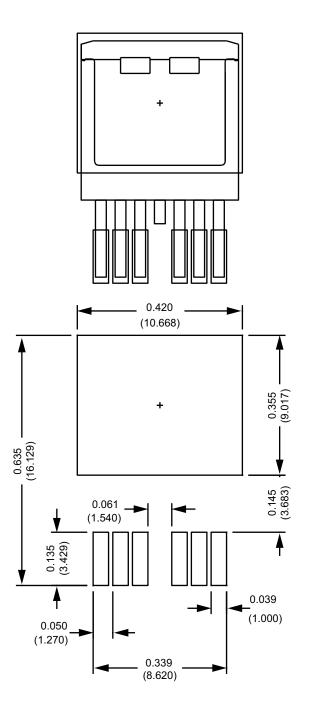


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PAD Pattern

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Recommended Land Pattern D²PAK (TO-263-7L)



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